Triacs

Silicon Bidirectional Thyristors

Designed primarily for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- All Diffused and Glass–Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance and High Heat Dissipation
- Center Gate Geometry for Uniform Current Spreading
- Gate Triggering Guaranteed in Four Modes
- **%** Indicates UL Registered File #E69369
- Device Marking: Logo, Device Type, e.g., MAC229A8FP, Date Code

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 110°C, Sine Wave 50 to 60 Hz, Gate Open)	VDRM, VRRM		Volts
MAC229A8FP MAC229A10FP		600 800	
On-State RMS Current (T _C = 80°C) Full Cycle Sine Wave 50 to 60 Hz	I _{T(RMS)}	8.0	Amps
Peak Non–Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _J = 110°C)	ITSM	80	Amps
Circuit Fusing Consideration (t = 8.3 ms)	I ² t	26	A ² s
Peak Gate Current $(t \le 2 \mu s, T_C = 80^{\circ}C)$	I _{GM}	±2.0	Amps
Peak Gate Voltage (t ≤ 2 μs, T _C = 80°C)	VGМ	±10	Volts
Peak Gate Power (t ≤ 2 μs,T _C = 80°C)	PGM	20	Watts
Average Gate Power $(T_C = 80^{\circ}C, t \leq 8.3 \text{ ms})$	PG(AV)	0.5	Watt
RMS Isolation Voltage ($T_A = 25^{\circ}C$, Relative Humidity $\leq 20\%$) (%)	V _(ISO)	1500	Volts
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C
Mounting Torque		8.0	in. lb.

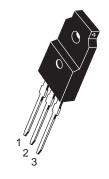
- (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.
- (2) The case temperature reference point for all TC measurements is a point on the center lead of the package as close as possible to the plastic body.



http://onsemi.com

ISOLATED TRIAC (9\) 8 AMPERES RMS 600 thru 800 VOLTS





ISOLATED TO-220 Full Pack CASE 221C STYLE 3

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		

ORDERING INFORMATION

Device	Package	Shipping
MAC229A8FP	ISOLATED TO220FP	500/Box
MAC229A10FP	ISOLATED TO220FP	500/Box

THERMAL CHARACTERISTICS

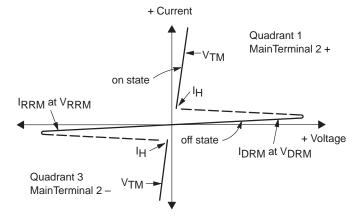
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	2.2	°C/W
Thermal Resistance, Case to Sink	$R_{\theta}CS$	2.2	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•	•	•	
Peak Repetitive Blocking Current ⁽¹⁾ (V _D = Rated V _{DRM} , V _{RRM} ; Open Gate)	T _J = 25°C T _J = 110°C	IDRM, IRRM	_		10 2.0	μA mA
ON CHARACTERISTICS						
Peak On-State Voltage (I _{TM} = ±11 A Peak, Pulse Width ≤ 2 ms, Duty Cycle	≤ 2%)	VTM		_	1.8	Volts
Gate Trigger Current (Continuous dc) $ (V_D=12~V,~R_L=100~\Omega) \\ MT2(+),~G(+);~MT2(+),~G(-);~MT2(-),~G(-) \\ MT2(-),~G(+) $		^I GT	=	_	10 20	mA
Gate Trigger Voltage (Continuous dc) $ (V_D=12~V,~R_L=100~\Omega) \\ MT2(+),~G(+);~MT2(+),~G(-);~MT2(-),~G(-) \\ MT2(-),~G(+) $		VGT		_	2.0 2.5	Volts
Gate Non–Trigger Voltage (Continuous dc) ($V_D = 12 \text{ V}, T_C = 110^{\circ}\text{C}, R_L = 100 \Omega$) All Four Quadrants		V _{GD}	0.2	_	_	Volts
Holding Current (VD = 12 Vdc, Initiating Current = ±200 mA, Gate Open)		lΗ	_	_	15	mA
Gate—Controlled Turn—On Time (V _D = Rated V _{DRM} , I _{TM} = 16 A Peak, I _G = 30 mA)		^t gt	_	1.5	_	μs
DYNAMIC CHARACTERISTICS						
Critical Rate of Rise of Off–State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, T _C = 110°C)		dv/dt	_	25	_	V/µs
Critical Rate of Rise of Commutation Voltage (V _D = Rated V _{DRM} , I _{TM} = 11.3 A, Commutating di/dt = 4.1 A/ms, Gate Unenergized, T _C = 80°C)		dv/dt(c)	_	5.0	_	V/µs

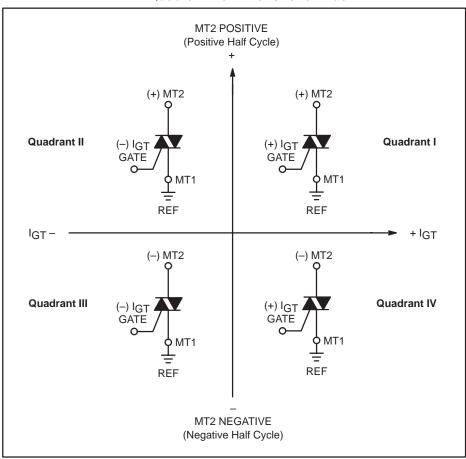
⁽¹⁾ Ratings apply for open gate conditions. Devices shall not be tested with a constant current source for blocking voltage such that the voltage applied exceeds the rated blocking voltage.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
lΗ	Holding Current

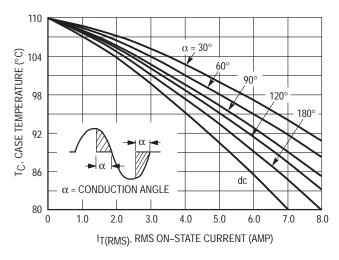


Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.





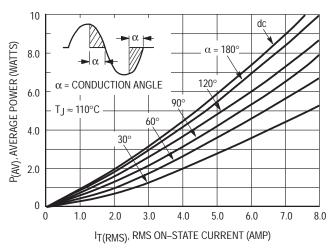
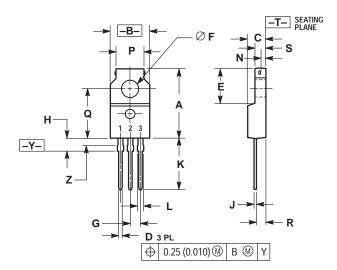


Figure 2. On-State Power Dissipation

PACKAGE DIMENSIONS

ISOLATED TO-220 Full Pack

CASE 221C-02 ISSUE C



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. LEAD DIMENSIONS UNCONTROLLED WITHIN DIMENSION Z.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.680	0.700	17.28	17.78
В	0.388	0.408	9.86	10.36
С	0.175	0.195	4.45	4.95
D	0.025	0.040	0.64	1.01
Ε	0.340	0.355	8.64	9.01
F	0.140	0.150	3.56	3.81
G	0.100	0.100 BSC		BSC
Н	0.110	0.155	2.80	3.93
J	0.018	0.028	0.46	0.71
K	0.500	0.550	12.70	13.97
L	0.045	0.070	1.15	1.77
N	0.049		1.25	
Р	0.270	0.290	6.86	7.36
Q	0.480	0.500	12.20	12.70
R	0.090	0.120	2.29	3.04
S	0.105	0.115	2.67	2.92
Z	0.070	0.090	1.78	2.28

STYLE 3: PIN 1. MT 1





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